TLC2274-HT 高级 LinCMOS™ 轨到轨运算放大器

1 特性

- 符合汽车应用要求
- 符合 AEC-Q100 标准
- 输出摆幅包括两个电源轨
- 低噪声 f = 1kHz 时典型值为 9nV/√Hz
- 低输入偏置电流：典型值 1pA
- 完全符合单电源及分离电源操作的要求
- 共模输入电压范围包括负轨
- 高增益带宽：典型值 2.2MHz
- 高转换率：典型值 3.6V/μs
- T_A = 25°C 时低输入偏移电压最大为 2500μV
- 包含宏观模型

2 应用

- 支持极限温度应用：
  - 受控基线
  - 同一组装和测试场所
  - 同一制造场所
  - 在极限（-40°C 至 150°C）温度范围内可用 (1)
  - 延长的产品生命周期
  - 延长的产品变更通知
  - 产品可追溯性
  - 德州仪器 (TI) 高温产品利用高度优化的硅（芯片）解决方案，通过设计和制造工艺方面的改进，能够在广泛的温度范围内最大限度提升性能。 所有器件在最高额定温度下均可连续正常运行 1000 小时。

(1) 可定制工作温度范围

3 说明

TLC2274 是一款由德州仪器 (TI) 生产的四通道运算放大器。 此器件在单电源或分离电源应用中表现出优异的轨到轨输出性能，能够进一步扩大动态范围。 TLC2274 带宽为 2MHz，转换率为 3V/μs，适用于高速应用。 这些器件能够提供出色的交流性能，其噪声、输入偏移电压和功耗均低于现有 CMOS 运算放大器。 TLC2274 的电压噪声为 9nV/√Hz，是竞争对手解决方案的二分之一。

TLC2274 放大器具有高输入阻抗和低噪声特性，是用于高阻抗源（如压电传感器）小信号调节的绝佳选择。 该器件属于微功耗级别，因此在手持式监控和遥感应用中运转良好。 此外，该器件的单电源或分离电源具有轨到轨输出特性，是与模数转换器 (ADC) 对接的理想选择。 该器件系列的额定工作电压为 5V 或 ±5V。

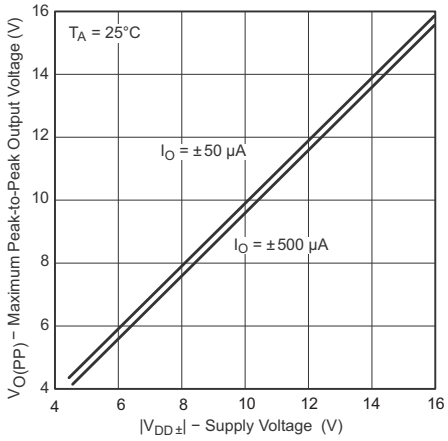
它可提供更大的输出动态范围，更低的电压噪声和更小的输入偏移电压。 凭借这一系列增强特性，该器件能够用于更广泛的应用。

器件信息(1)

器件型号	封装	封装尺寸（标称值）
TLC2274-HT	TSSOP (14)	6.60mm x 5.10mm

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

最大峰峰值输出电压与电源电压



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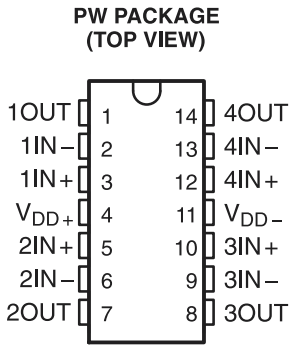
4 修订历史记录

日期	修订版本	注释
2015 年 1 月	*	最初发布。

5 Pin Configuration and Functions



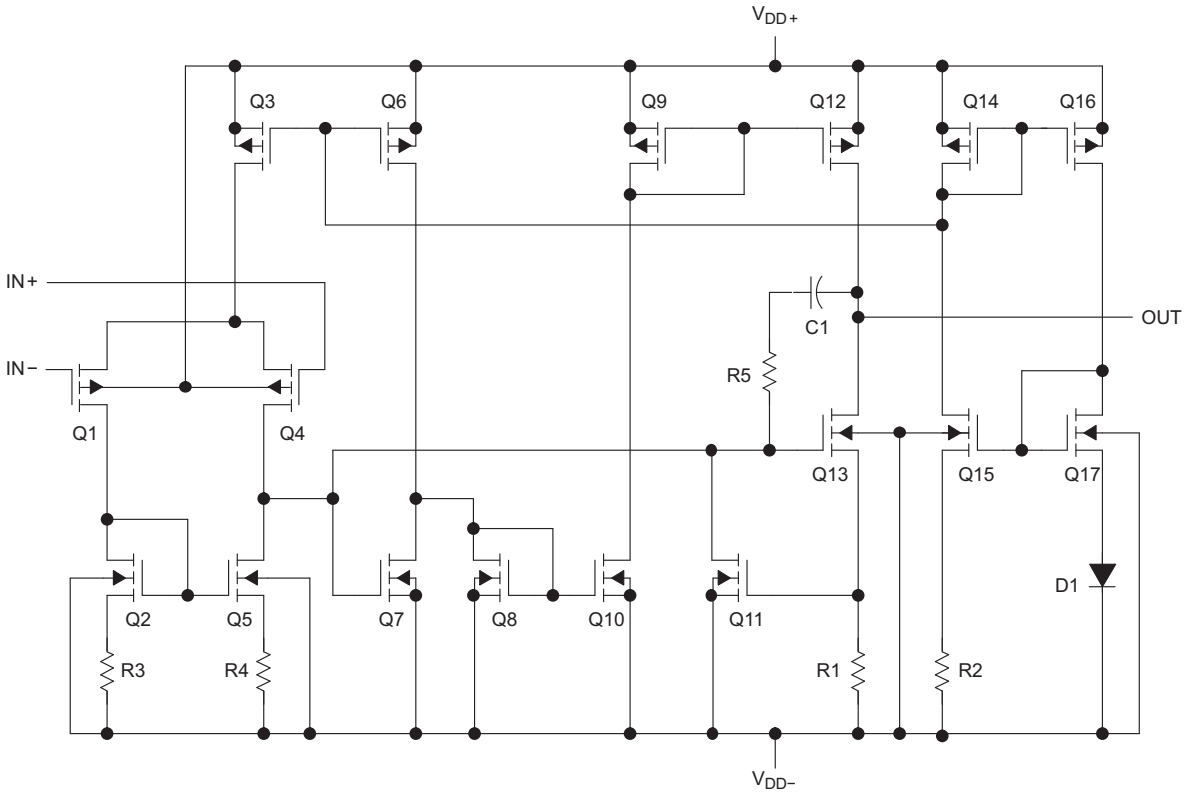


Figure 1. Equivalent Schematic (Each Amplifier)

Table 1. Actual Device Component Count(1)

COMPONENT	TLC2274
Transistors	76
Resistors	52
Diodes	18
Capacitors	6

(1) Includes both amplifiers and all ESD, bias, and trim circuitry

6 Specifications

6.1 Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{DD+}	Supply voltage(2)			8	V
V_{DD-}	Supply voltage(2)			–8	V
V_{ID}	Differential input voltage(3)		–16	16	V
V_I	Input voltage(2)	Any input	V_{DD-} – 0.3	V_{DD+}	V
I_I	Input current	Any input	–5	5	mA
I_O	Output current		–50	50	mA
	Total current into V_{DD+}		–50	50	mA
	Total current out of V_{DD-}		–50	50	mA
	Duration of short-circuit current at (or below) 25°C(4)		Unlimited		
T_A	Operating free-air temperature		–40	150	°C
	Lead temperature 1.6 mm (1/16 inch) from case for 10 s			260	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltage values, except differential voltages, are with respect to the midpoint between V_{DD+} and V_{DD-}.
(3) Differential voltages are at I_{N+} with respect to I_{N-}. Excessive current will flow if input is brought below V_{DD-} – 0.3 V.
(4) The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

6.2 ESD Ratings

				VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002(1)		±2500	V
		Charged-device model (CDM), per AEC Q100-011	All pins	±1500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{DD\pm}$	Supply voltage	±2.2	±8	V
V_I	Input voltage	V_{DD-}	V_{DD+} −1.5	V
V_{IC}	Common-mode input voltage	V_{DD-}	V_{DD+} −1.5	V
T_A	Operating free-air temperature	−40	150	°C

6.4 Thermal Information

THERMAL METRIC(1)		TLC2274 PW 14 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	106.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	35.5	
$R_{\theta JB}$	Junction-to-board thermal resistance	47.6	
ψ_{JT}	Junction-to-top characterization parameter	2.4	
ψ_{JB}	Junction-to-board characterization parameter	47.1	

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics, V_{DD} = 5 V

at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_{IC} = 0 V, V_O = 0 V,	$V_{DD\pm}$ = ±2.5 V, R_S = 50 Ω	25°C		300	2500	µV
				Full range			3000	
αV_{IO}	Temperature coefficient of input offset voltage			25°C to 125°C		2		µV/°C
	Input offset voltage long-term drift (2)			25°C		0.002		µV/mo
I_{IO}	Input offset current			25°C		0.5	60	pA
				Full range			7000	
I_{IB}	Input bias current			25°C		1		pA
				Full range				
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω	$\lvert V_{IO}\rvert \le$ 5 mV	25°C	0 to 4	−0.3 to 4.2		V
				Full range	0 to 3.5			
V_{OH}	High-level output voltage	I_{OH} = −20 µA		25°C		4.99		V
		I_{OH} = −200 µA		25°C	4.85	4.93		
				Full range	4.84			
		I_{OH} = −1 mA		25°C	4.25	4.65		
				Full range	4.20			
V_{OL}	Low-level output voltage	V_{IC} = 2.5 V,	I_{OL} = 50 µA	25°C		0.01		V
		V_{IC} = 2.5 V,	I_{OL} = 500 µA	25°C		0.09	0.15	
				Full range			0.16	
		V_{IC} = 2.5 V,	I_{OL} = 5 mA	25°C		0.9	1.5	
				Full range			1.6	
A_{VD}	Large-signal differential voltage amplification	V_{IC} = 2.5 V, V_O = 1 V to 4 V,	R_L = 10 kΩ (3)	25°C	10	35		V/mV
				Full range	8			
			R_L = 1 MΩ (3)	25°C		175		
r_{id}	Differential input resistance			25°C		10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	N package	25°C		8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	A_V = 10	25°C		140		Ω
CMRR	Common-mode rejection ratio	V_{IC} = 0 V to 2.7 V, V_O = 2.5 V,	R_S = 50 Ω	25°C	70	75		dB
				Full range	69			
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	V_{DD} = 4.4 V to 16 V,		25°C	80	95		dB
		V_{IC} = V_{DD}/2,	No load	Full range	80			
I_{DD}	Supply current	V_O = 2.5 V,	No load	25°C		4.4	6	mA
				Full range			6	

(1) Full range is −40°C to 150°C for thisl part.
(2) Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.
(3) Referenced to 2.5 V

6.6 Operating Characteristics, V_{DD} = 5 V

at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V_O = 0.5 V to 2.5 V, C_L = 100 pF (2)	R_L = 10 kΩ (2)	25°C	2.3	3.6		V/μs
				Full range	1.2			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50		nV/√Hz
		f = 1 kHz		25°C		9		
$V_{N(pp)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz		25°C		1		μV
		f = 0.1 to 10 Hz		25°C		1.4		
I_n	Equivalent input noise current			25°C		0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = 0.5V to 2.5V, R_L = 10 kΩ, f = 20 kHz (2)	A_V = 1	25°C		0.0013%		
			A_V = 10			0.004%		
			A_V = 100			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF (2)	R_L = 10 kΩ (2)	25°C		2.18		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 2V, R_L = 10 kΩ (2)	A_V = 1, C_L = 100 pF (2)	25°C		1		MHz
t_s	Settling time	A_V = -1, Step = 0.5V to 2.5V, R_L = 10 kΩ (2) C_L = 100 pF (2)	To 0.1%	25°C		1.5		μs
			To 0.01%			2.6		
φ_m	Phase margin at unity gain	R_L = 10 kΩ	C_L = 100 pF (2)	25°C		50°		
	Gain margin			25°C		10		dB

(1) Full range is −40°C to 150°C for this part.
(2) Referenced to 2.5 V

6.7 Electrical Characteristics, $V_{DD±}$ = ±5 V

at specified free-air temperature, $V_{DD±}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	V_{IC} = 0 V, R_S = 50 Ω	V_O = 0 V	25°C		300	2500	µV
				Full range			3000	
$αV_{IO}$	Temperature coefficient of input offset voltage			25°C to 125°C		2		µV/°C
	Input offset voltage long-term drift (2)			25°C		0.002		µV/mo
I_{IO}	Input offset current			25°C		0.5	60	pA
				Full range			7000	
I_{IB}	Input bias current			25°C		1	60	pA
				Full range			7000	
V_{ICR}	Common-mode input voltage range	R_S = 50 Ω	$\|V_{IO}\| ≤ 5$ mV	25°C	−5 to 4	−5.3 to 4.2		V
				Full range	−5 to 3.5			
V_{OM+}	Maximum positive peak output voltage	I_O = −20 µA		25°C		4.99		V
		I_O = −200 µA		25°C	4.85	4.93		
				Full range	4.84			
		I_O = −1 mA		25°C	4.25	4.65		
				Full range	4.20			
V_{OM-}	Maximum negative peak output voltage	V_{IC} = 0 V,	I_O = 50 µA	25°C		−4.99		V
		V_{IC} = 0 V,	I_O = 500 µA	25°C	−4.85	−4.91		
				Full range	−4.85			
		V_{IC} = 0 V,	I_O = 5 mA	25°C	−3.5	−4.1		
				Full range	−3.45			
A_{VD}	Large-signal differential voltage amplification	V_O = ±4 V,	R_L = 10 kΩ	25°C	20	50		V/mV
				Full range	16			
			R_L = 1 MΩ	25°C		300		
r_{id}	Differential input resistance			25°C		10^{12}		Ω
r_i	Common-mode input resistance			25°C		10^{12}		Ω
c_i	Common-mode input capacitance	f = 10 kHz,	N package	25°C		8		pF
z_o	Closed-loop output impedance	f = 1 MHz,	AV = 10	25°C		130		Ω
CMRR	Common-mode rejection ratio	V_{IC} = -5 V to 2.7 V, V_O = 0 V,	R_S = 50 Ω	25°C	75	80		dB
				Full range	73			
k_{SVR}	Supply voltage rejection ratio ($ΔV_{DD}/ΔV_{IO}$)	V_{DD} = ±2.2 V to ±8 V, V_{IC} = 0V,	No load	25°C	80	95		dB
				Full range	80			
I_{DD}	Supply current	V_O = 0 V,	No load	25°C		4.4	6	mA
				Full range			6	

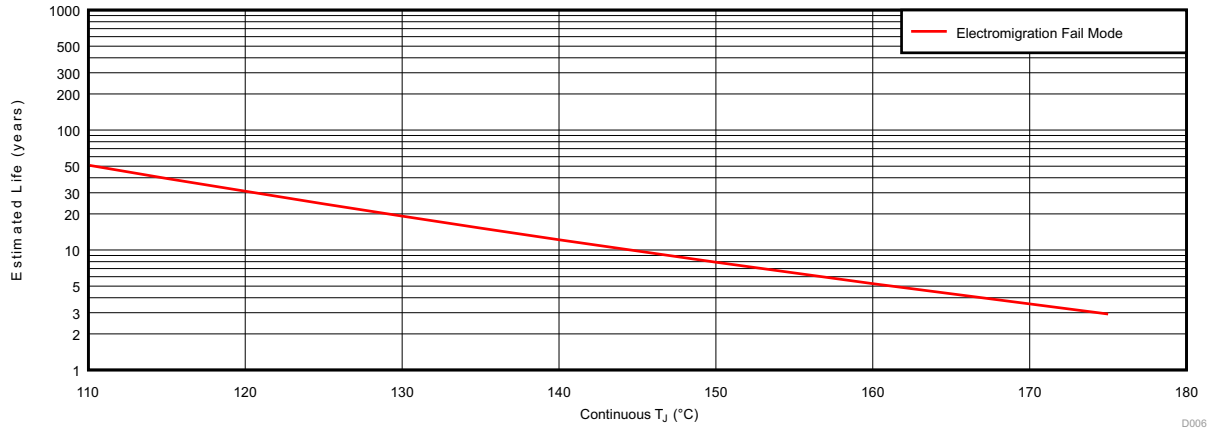
(1) Full range is −40°C to 150°C for this part.
(2) Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T_A = 150°C extrapolated to T_A = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

6.8 Operating Characteristics, $V_{DD±}$ = ±5 V

at specified free-air temperature, $V_{DD±}$ = ±5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T_A (1)	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V_O = ±2.3 V, R_L = 10 kΩ	C_L = 100 pF	25°C	2.3	3.6		V/μs
				Full range	1.2			
V_n	Equivalent input noise voltage	f = 10 Hz		25°C		50		nV/√Hz
		f = 1 kHz		25°C		9		
$V_{N(pp)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz		25°C		1		μV
		f = 0.1 to 10 Hz		25°C		1.4		
I_n	Equivalent input noise current			25°C		0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise	V_O = ±2.3 V, f = 20 kHz, R_L = 10 kΩ	A_V = 1	25°C		0.0011%		
			A_V = 10			0.004%		
			A_V = 100			0.03%		
	Gain-bandwidth product	f = 10 kHz, C_L = 100 pF	R_L = 10 kΩ	25°C		2.25		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)}$ = 4.6 V, R_L = 10 kΩ	A_V = 1, C_L = 100 pF	25°C		0.54		MHz
t_s	Settling time	A_V = -1, Step = -2.3 V to 2.3 V, R_L = 10 kΩ C_L = 100 pF	To 0.1%	25°C		1.5		μs
			To 0.01%			3.2		
φ_m	Phase margin at unity gain	R_L = 10 kΩ,	C_L = 100 pF	25°C		52°		
	Gain margin			25°C		10		dB

(1) Full range is −40°C to 150°C for this part.



A. See data sheet for *Absolute Maximum Ratings* and minimum *Recommended Operating Conditions*.

B. Silicon operating life design goal is 10 years at 105°C junction temperature (does not include package interconnect life).

Figure 2. TLC2274EPWRQ1 Operating Life Derating Chart

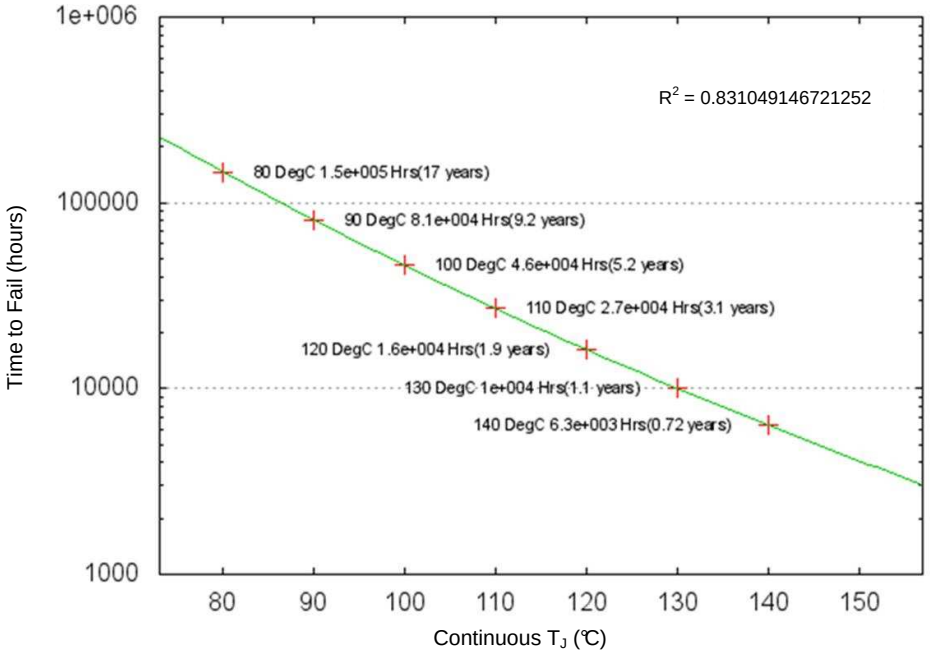


Figure 3. Estimated Wire Bond Life

6.9 Typical Characteristics

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the devices.

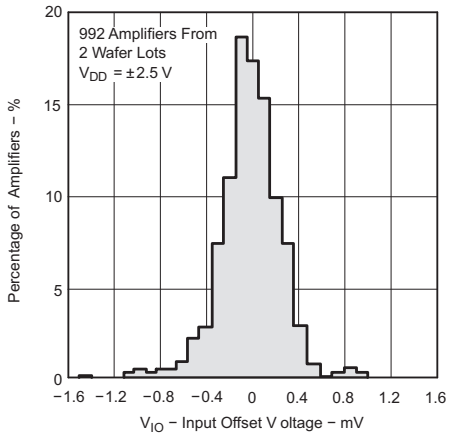


Figure 4. Distribution of TLC2274 Input Offset Voltage

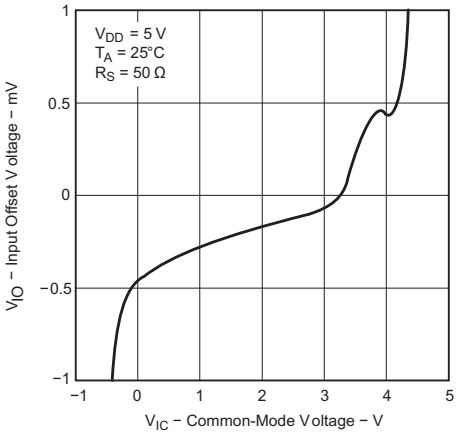


Figure 5. Input Offset Voltage vs Common-Mode Voltage

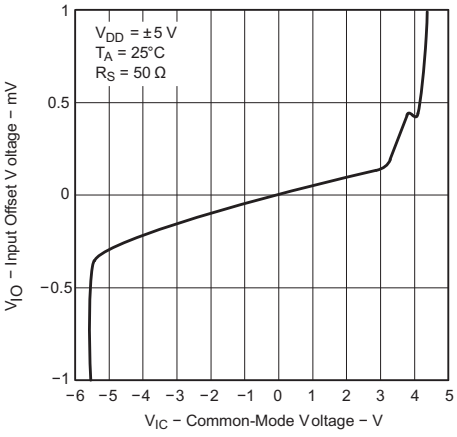


Figure 6. Input Offset Voltage vs Common-Mode Voltage

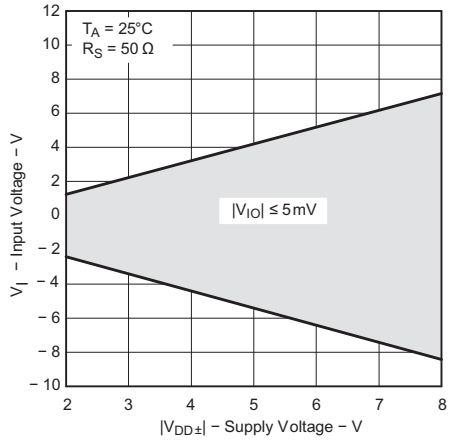


Figure 7. Input Voltage vs Supply Voltage

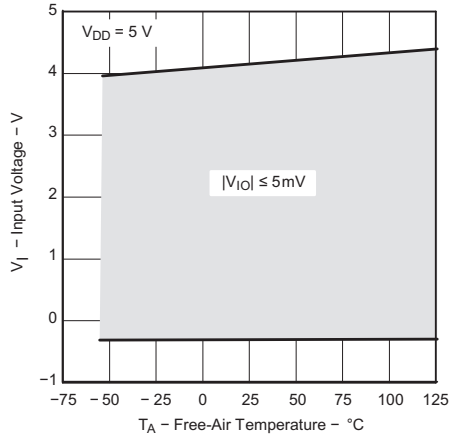


Figure 8. Input Voltage vs Free-Air Temperature

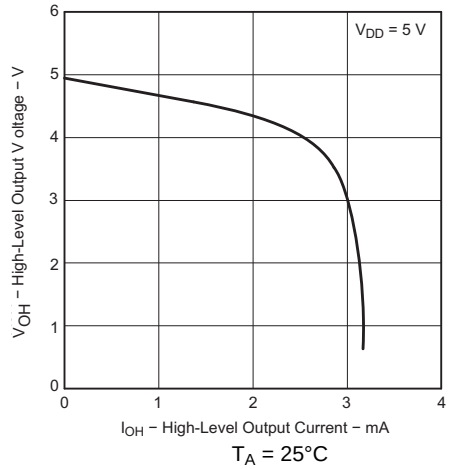


Figure 9. High-Level Output Voltage vs High-Level Output Current

Typical Characteristics (continued)

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the devices.

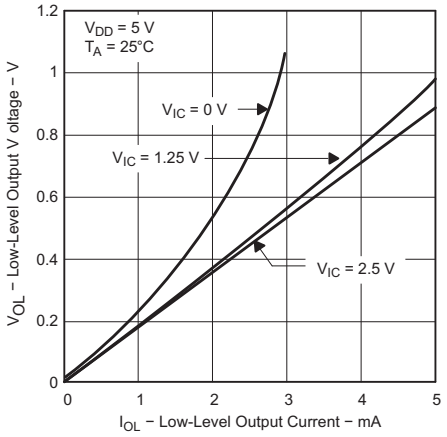


Figure 10. Low-Level Output Voltage vs Low-Level Output Current

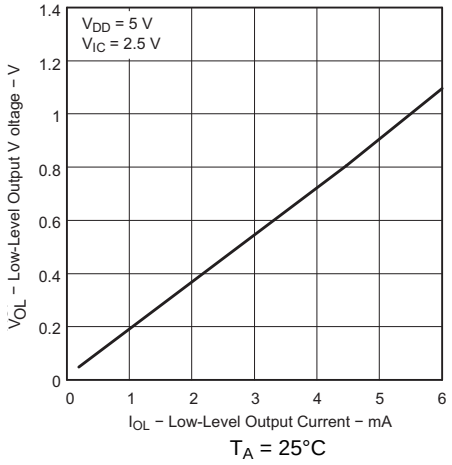


Figure 11. Low-Level Output Voltage vs Low-Level Output Current

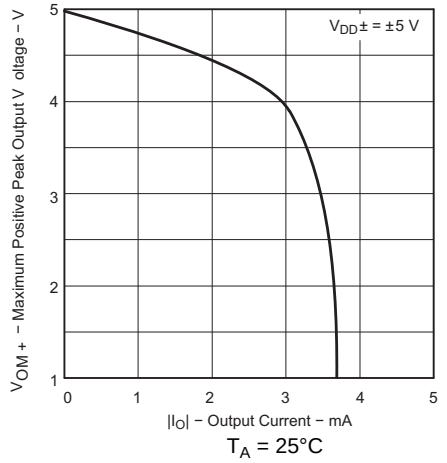


Figure 12. Maximum Positive Peak Output Voltage vs Output Current

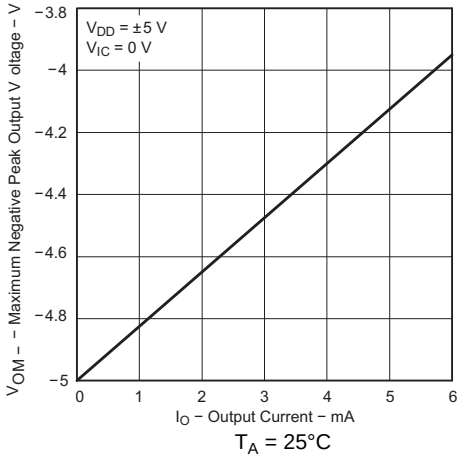


Figure 13. Maximum Negative Peak Output Voltage vs Output Current

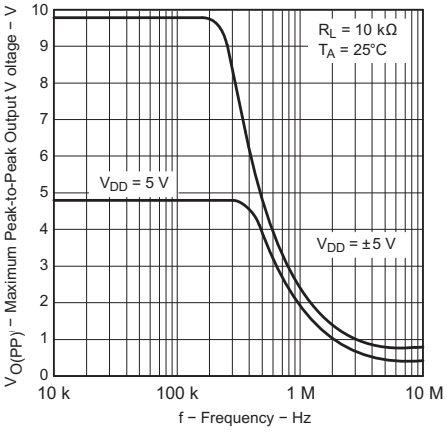


Figure 14. Maximum Peak-to-Peak Output Voltage vs Frequency

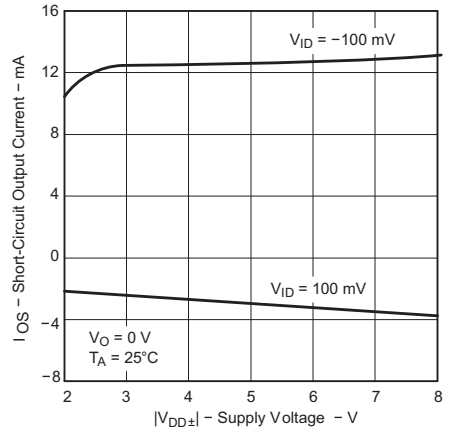


Figure 15. Short-Circuit Output Current vs Supply Voltage

Typical Characteristics (continued)

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the devices.

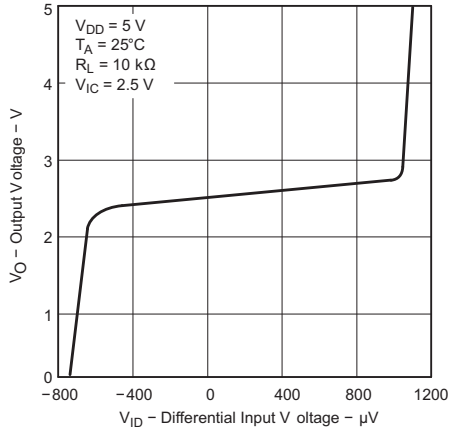


Figure 16. Output Voltage vs Differential Input Voltage

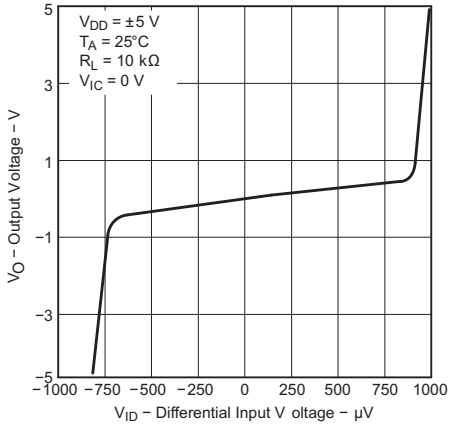


Figure 17. Output Voltage vs Differential Input Voltage

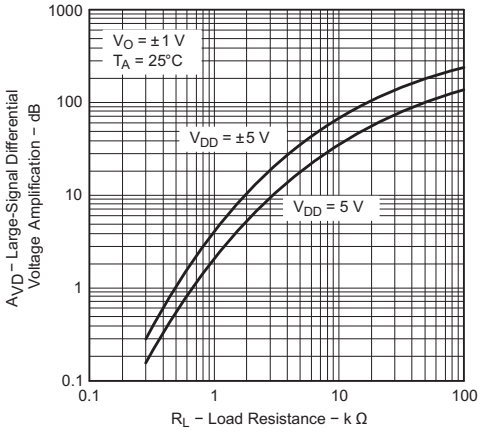


Figure 18. Large-Signal Differential Voltage Amplification vs Load Resistance

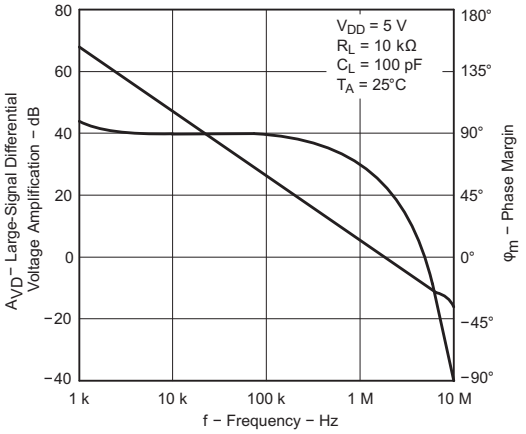


Figure 19. Large-Signal Differential Voltage Amplification and Phase Margin vs Frequency

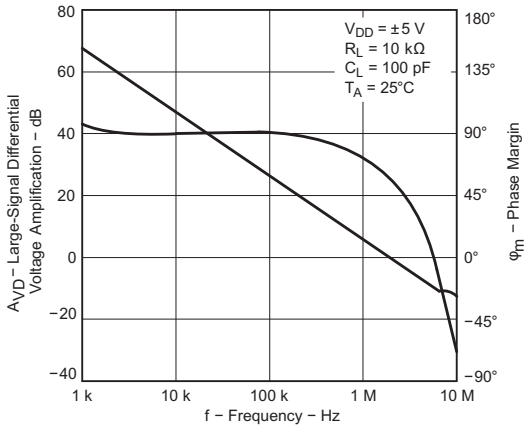


Figure 20. Large-Signal Differential Voltage Amplification and Phase Margin vs Frequency

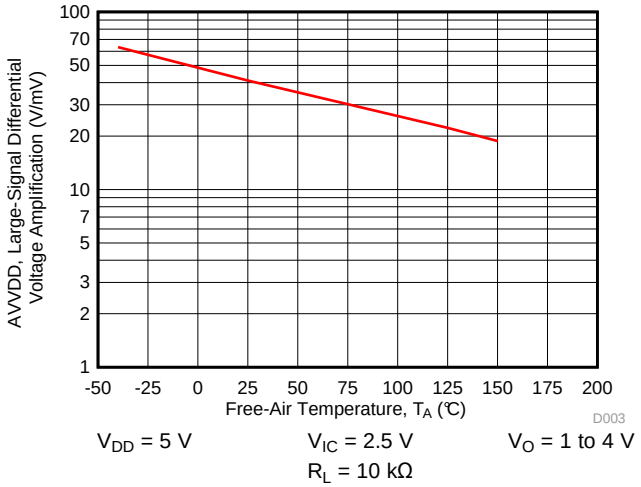


Figure 21. Large-Signal Differential Voltage Amplification vs Free-Air Temperature

Typical Characteristics (continued)

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the devices.

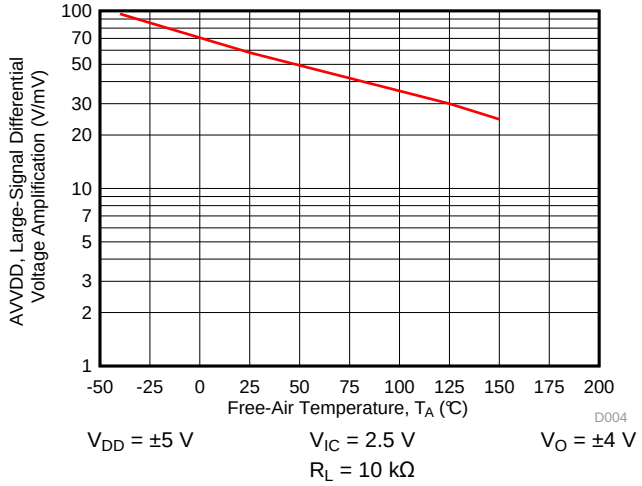


Figure 22. Large-Signal Differential Voltage Amplification vs Free-Air Temperature

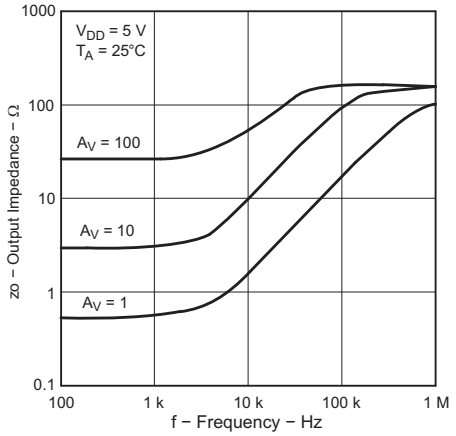


Figure 23. Output Impedance vs Frequency

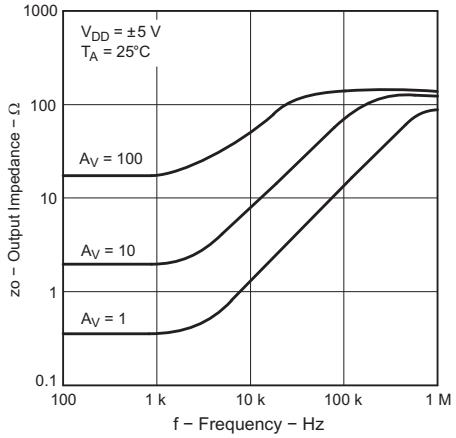


Figure 24. Output Impedance vs Frequency

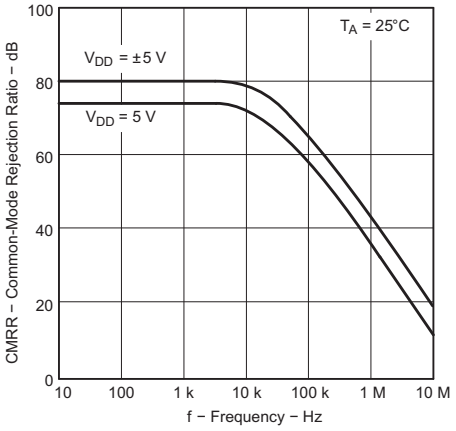


Figure 25. Common-Mode Rejection Ratio vs Frequency

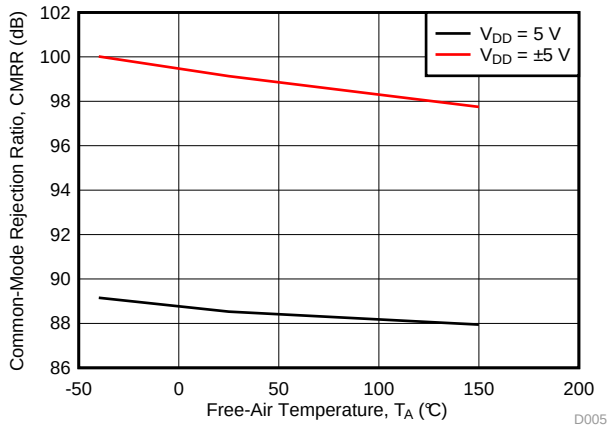


Figure 26. Common-Mode Rejection Ratio vs Free-Air Temperature

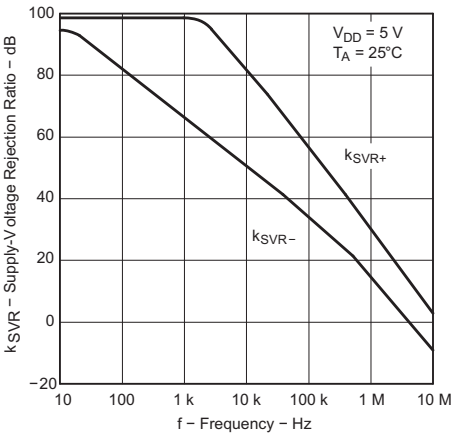


Figure 27. Supply-Voltage Rejection Ratio vs Frequency

Typical Characteristics (continued)

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the devices.

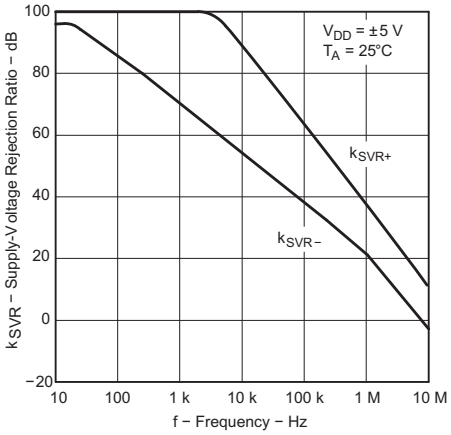
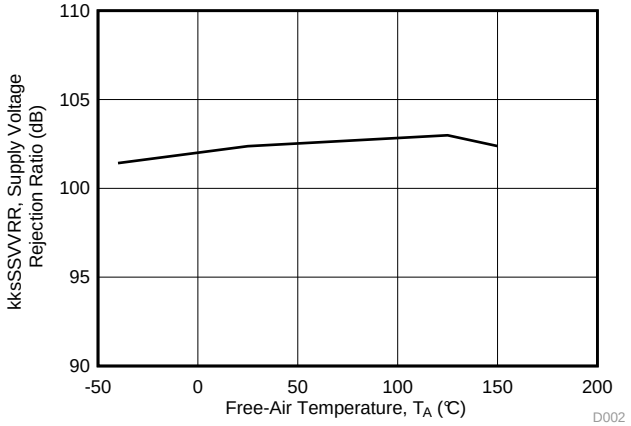


Figure 28. Supply-Voltage Rejection Ratio vs Frequency



$V_{DD±}$ = ±2.2 to ±8 V V_O = 0 V

Figure 29. Supply-Voltage Rejection Ratio vs Free-Air Temperature

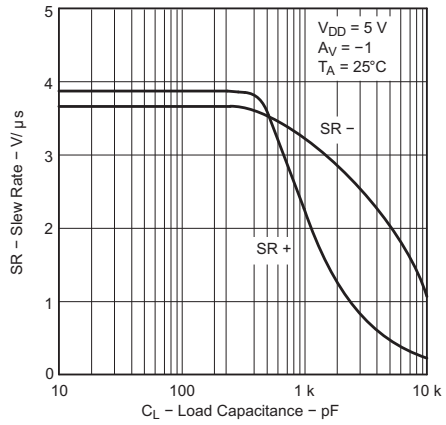
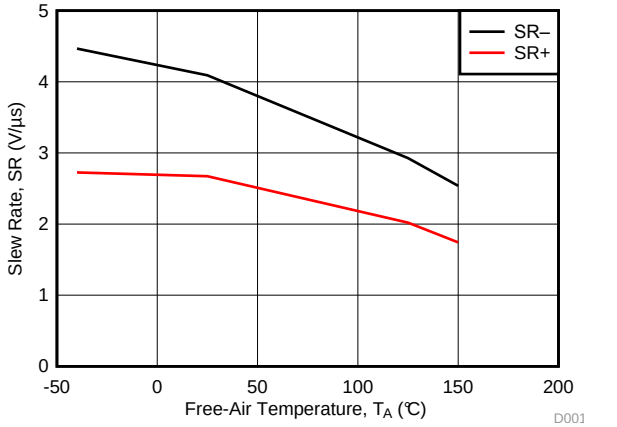


Figure 30. Slew Rate vs Load Capacitance



V_{DD} = 5 V R_L = 10 kΩ C_L = 100 pF
A_V = 1

Figure 31. Slew Rate vs Free-Air Temperature

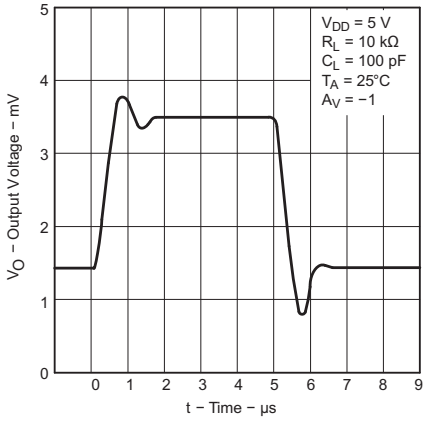


Figure 32. Inverting Large-Signal Pulse Response

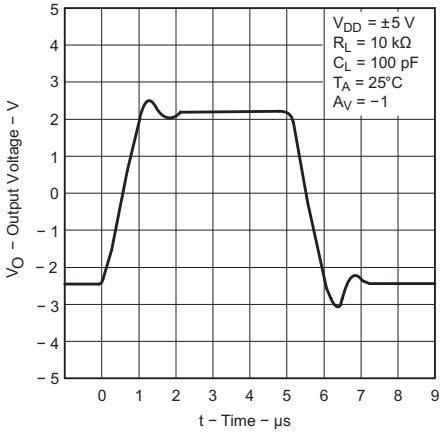


Figure 33. Inverting Large-Signal Pulse Response

Typical Characteristics (continued)

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the devices.

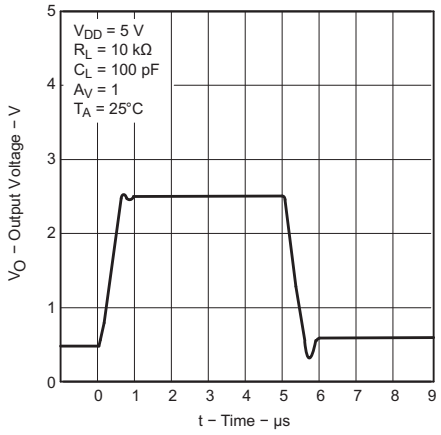


Figure 34. Voltage-Follower Large-Signal Pulse Response

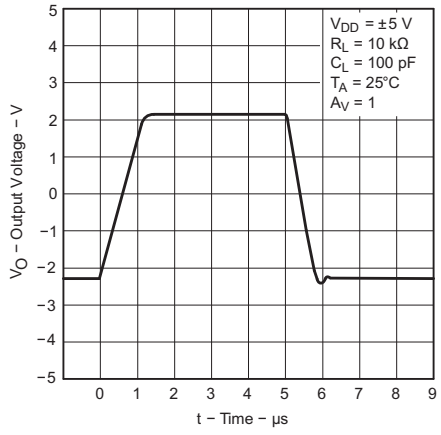


Figure 35. Voltage-Follower Large-Signal Pulse Response

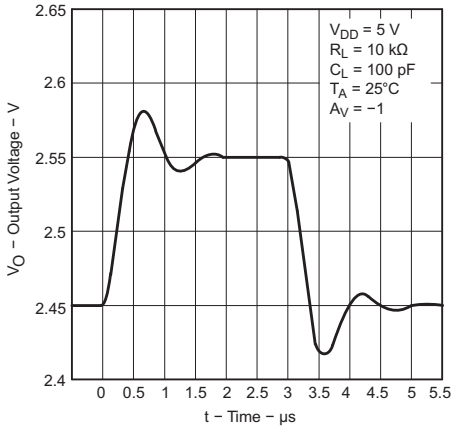


Figure 36. Inverting Small-Signal Pulse Response

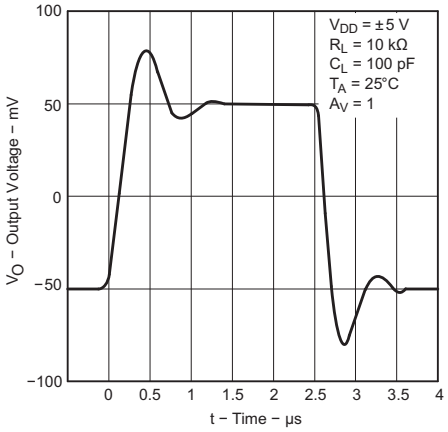


Figure 37. Inverting Small-Signal Pulse Response

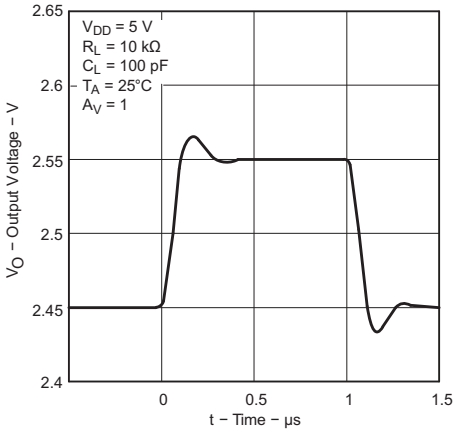


Figure 38. Voltage-Follower Small-Signal Pulse Response

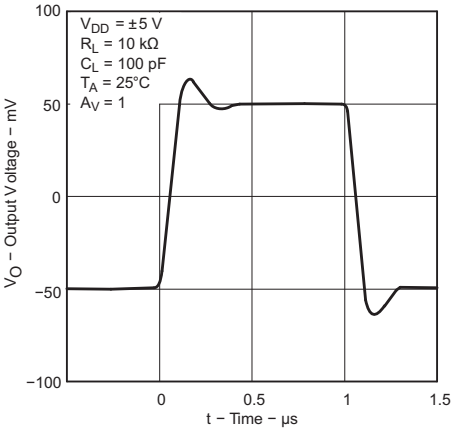


Figure 39. Voltage-Follower Small-Signal Pulse Response

Typical Characteristics (continued)

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the devices.

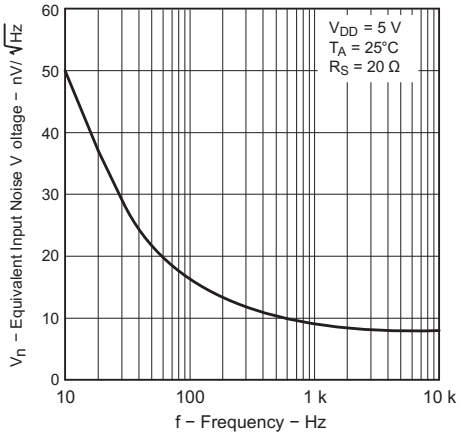


Figure 40. Equivalent Input Noise Voltage vs Frequency

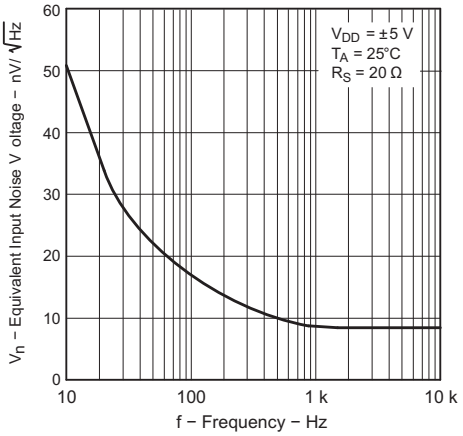


Figure 41. Equivalent Input Noise Voltage vs Frequency

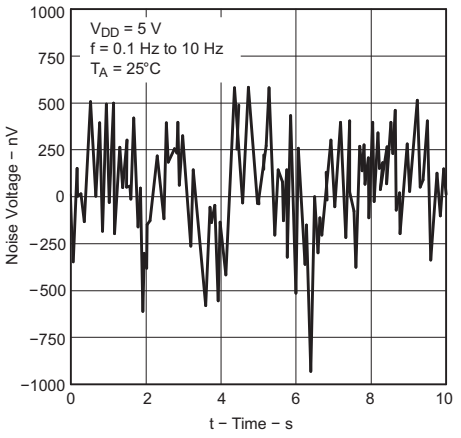


Figure 42. Noise Voltage Over a 10-s Period

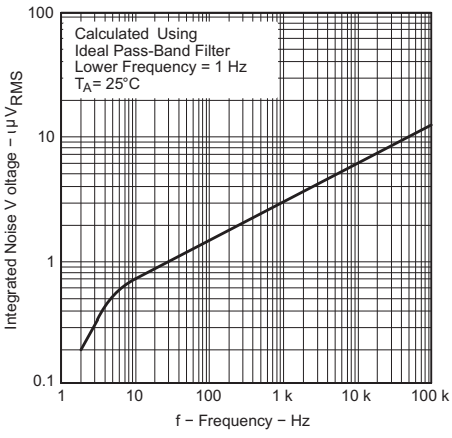


Figure 43. Integrated Noise Voltage vs Frequency

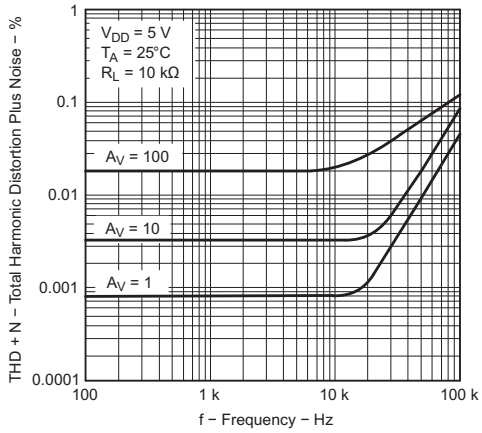


Figure 44. Total Harmonic Distortion Plus Noise vs Frequency

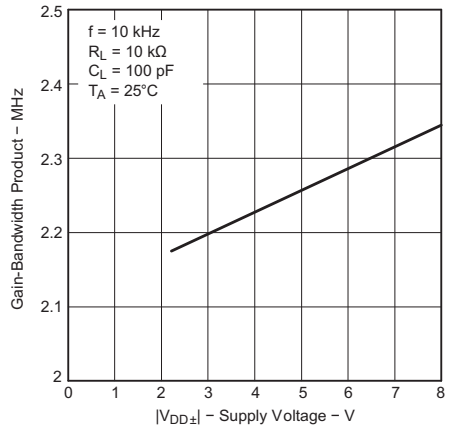


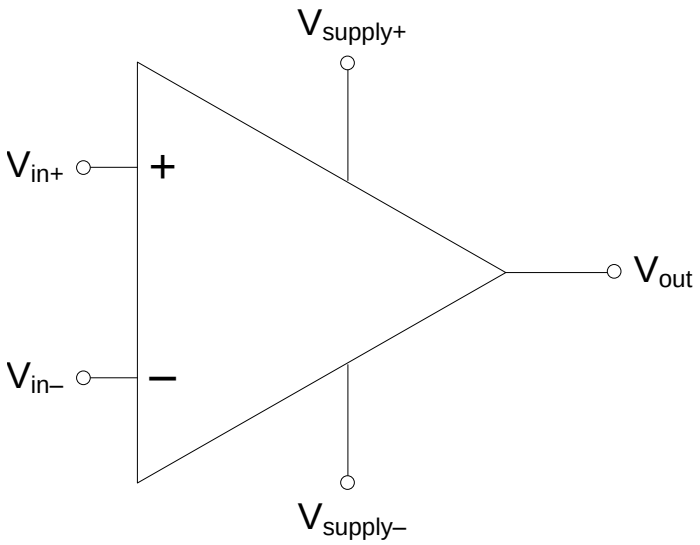
Figure 45. Gain-Bandwidth Product vs Supply Voltage

7 Detailed Description

7.1 Overview

The TLC2274 device exhibits rail-to-rail output performance for increased dynamic range in single- or split -supply applications. These device offers comparable ac performance while having better noise, input offset voltage and power dissipation than existing CMOS operational amplifiers. The TLC2274 device, exhibiting high input impedance and low noise, is excellent for small signal conditioning for high-impedance sources, such as piezoelectric transducers. It offers increased output dynamic range, lower noise voltage, and lower input offset voltage. This enhanced feature set allows the device to be used in a wider range of applications.

7.2 Functional Block Diagram



7.3 Feature Description

These devices use the Texas Instruments silicon gate LinCMOS™ process, giving them stable input offset voltages, very high input impedances, and extremely low input offset and bias currents. In addition, the rail-to-rail output feature with single- or split-supplies, makes this device a great choice when interfacing with analog-to-digital converters (ADCs).

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

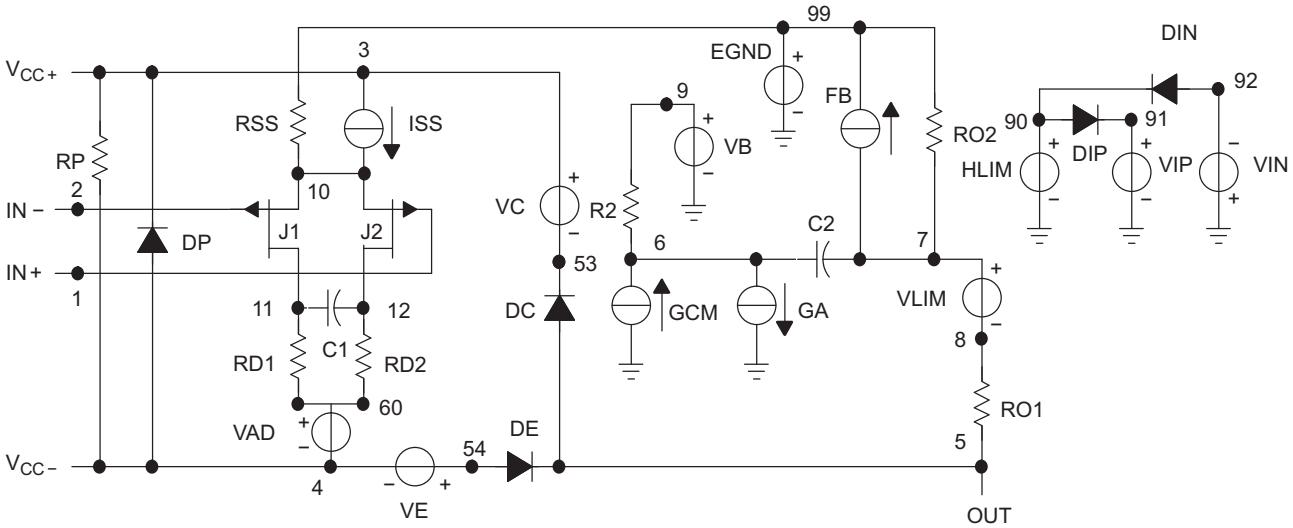
8.1.1 Macromodel Information

Macromodel information provided was derived using Microsim Parts, the model generation software used with Microsim PSpice. The Boyle macromodel (1) and subcircuit in Figure 46 are generated using the TLC227x typical electrical and operating characteristics at T_A = 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

(1) G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", IEEE Journal of Solid-State Circuits, SC-9, 353 (1974).

Application Information (continued)




```
.SUBCKT TLC227x 1 2 3 4 5
C1      11      1214E−12
C2      6       760.00E−12
DC      5       53DX
DE      54      5DX
DLP     90      91DX
DLN     92      90DX
DP      4       3DX
EGND    99      0POLY (2) (3,0) (4,) 0 .5 .5
FB      99      0POLY (5) VB VC VE VLP VLN 0
+ 984.9E3 −1E6 1E6 1E6 −1E6
GA      6       011 12 377.0E−6
GCM 0 6 10 99 134E−9
ISS     3       10DC 216.OE−6
HLIM    90      0VLIM 1K
J1      11      210 JX
J2      12      110 JX
R2      6       9100.OE3
RD1     60      112.653E3
RD2     60      122.653E3
R01     8       550
R02     7       9950
RP      3       44.310E3
RSS     10      99925.9E3
VAD     60      4−.5
VB      9       0DC 0
VC 3 53 DC .78
VE      54      4DC .78
VLIM    7       8DC 0
VLP     91      0DC 1.9
VLN     0       92DC 9.4
.MODEL DX D (IS=800.0E−18)
.MODEL JX PJF (IS=1.500E−12BETA=1.316E-3
+ VTO=−.270)
.ENDS
```

Figure 46. Boyle Macromodels and Subcircuit

8.2 Typical Application

The TLC2274 is designed to drive larger capacitive loads than most CMOS operational amplifiers. Figure 48 and Figure 49 show its ability to drive loads up to 1000 pF while maintaining good gain and phase margins (Rnull = 0).

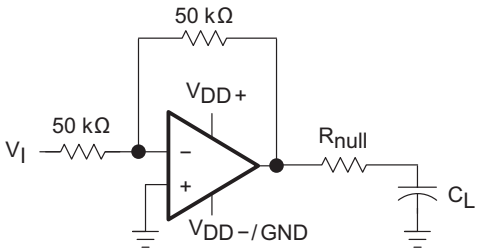


Figure 47. Typical Application Schematic

Typical Application (continued)

8.2.1 Design Requirements

As per Equation 1:

Table 2. Design Parameters

Improvement in Phase Margin	UGBW (kHz)	R null (Ω)	CL (pF)
0	1000	0	1000
7.15	1000	20	1000
17.43	1000	50	1000
32.12	1000	100	1000

8.2.2 Detailed Design Procedure

A smaller series resistor (R_{null}) at the output of the device (see Figure 47) improves the gain and phase margins when driving large capacitive loads. Figure 48 and Figure 49 show the effects of adding series resistances of 10 Ω, 50 Ω, 100 Ω, 200 Ω, and 500 Ω. The addition of this series resistor has two effects: the first is that it adds a zero to the transfer function and the second is that it reduces the frequency of the pole associated with the output load in the transfer function.

The zero introduced to the transfer function is equal to the series resistance times the load capacitance. To calculate the improvement in phase margin, Equation 1 can be used.

$$\Delta\varphi_{m1} = \tan^{-1}(2 \times \pi \times UGBW \times R_{null} \times C_L) \quad (1)$$

where

- Δφm1 = Improvement in phase margin
- UGBW = Unity-gain bandwidth frequency
- Rnull = Output series resistance
- CL = Load capacitance

The unity-gain bandwidth (UGBW) frequency decreases as the capacitive load increases (see Figure 47). To use equation 1, UGBW must be approximated from Figure 47. Using Equation 1 alone overestimates the improvement in phase margin, as illustrated in Figure 51. The overestimation is caused by the decrease in the frequency of the pole associated with the load, thus providing additional phase shift and reducing the overall improvement in phase margin. Using Figure 47, with Equation 1 enables the designer to choose the appropriate output series resistance to optimize the design of circuits driving large capacitance loads.

8.2.3 Application Curves

T_A = 25°C

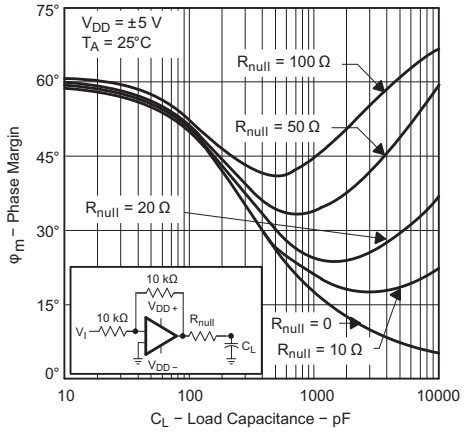


Figure 48. Phase Margin vs Load Capacitance

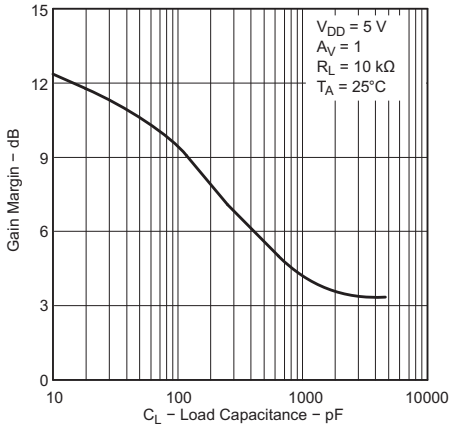


Figure 49. Gain Margin vs Load Capacitance

T_A = 25°C

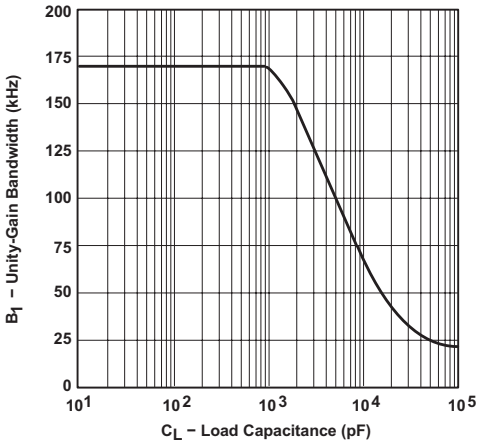


Figure 50. Unity-Gain Bandwidth vs Load Capacitance

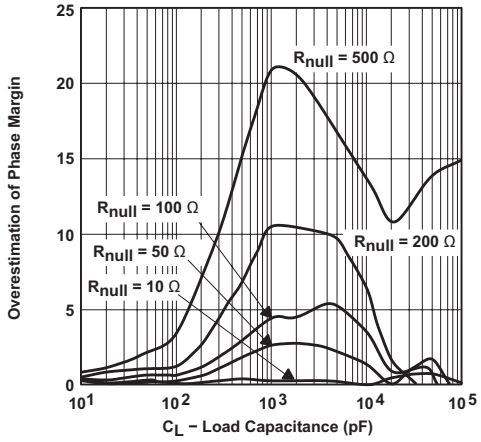


Figure 51. Overestimation of Phase Margin vs Load Capacitance

9 Power Supply Recommendations

TLC2274 operates from ±2.2- to ±8-V. In addition, key parameters are assured over the specified temperature range, –55°C to 125°C. Parameters which vary significantly with operating voltage or temperature are shown in the *Typical Characteristics*.

10 Layout

10.1 Layout Guidelines

The TLC2274 has very-low offset voltage and drift. To achieve highest performance, optimize circuit layout and mechanical conditions. Offset voltage and drift can be degraded by small thermoelectric potentials at the operational amplifier inputs. Connections of dissimilar metals generate thermal potential, which can degrade the ultimate performance of the TLC2274. Cancel these thermal potentials by assuring that they are equal in both input terminals.

- Keep the thermal mass of the connections made to the two input terminals similar.
- Locate heat sources as far as possible from the critical input circuitry.
- Shield operational amplifier and input circuitry from air currents such as cooling fans.

10.2 Layout Example

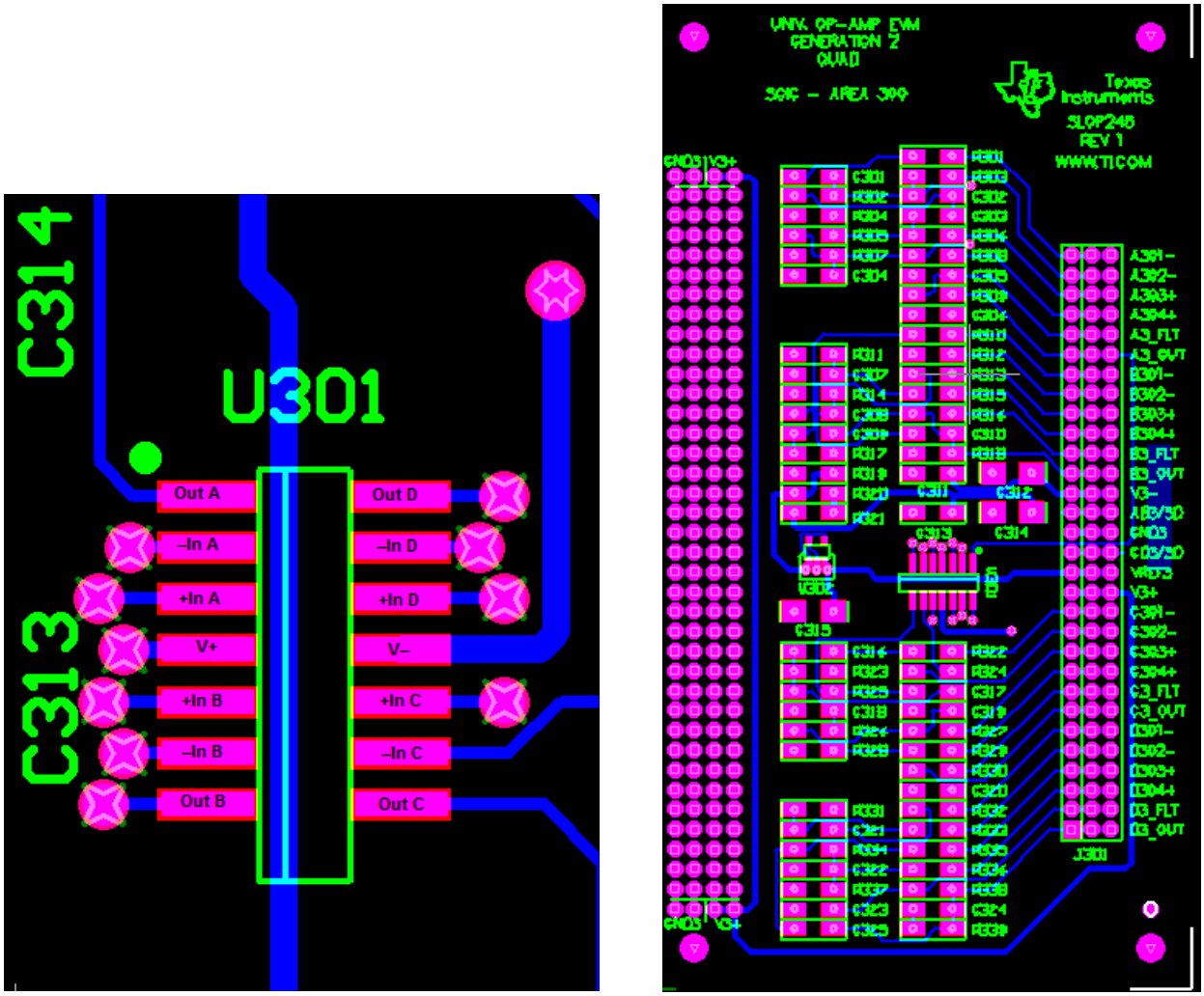


Figure 52. Board Layout Example

11 器件和文档支持

11.1 商标

LinCMOS is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.2 静电放电警告

这些装置包含有限的内置 ESD 保护。 存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

11.3 术语表

SLYZ022 — *TI 术语表*。

这份术语表列出并解释术语、首字母缩略词和定义。

12 机械封装和可订购信息

以下页中包括机械封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLC2274EPWRQ1	Active	Production	TSSOP (PW) | 14	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	2274EQ1
TLC2274EPWRQ1.A	Active	Production	TSSOP (PW) | 14	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	2274EQ1
TLC2274EPWRQ1.B	Active	Production	TSSOP (PW) | 14	2000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	2274EQ1

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

OTHER QUALIFIED VERSIONS OF TLC2274-HT :

- Catalog : TLC2274

- Automotive : TLC2274-Q1
- Enhanced Product : TLC2274-EP

NOTE: Qualified Version Definitions:

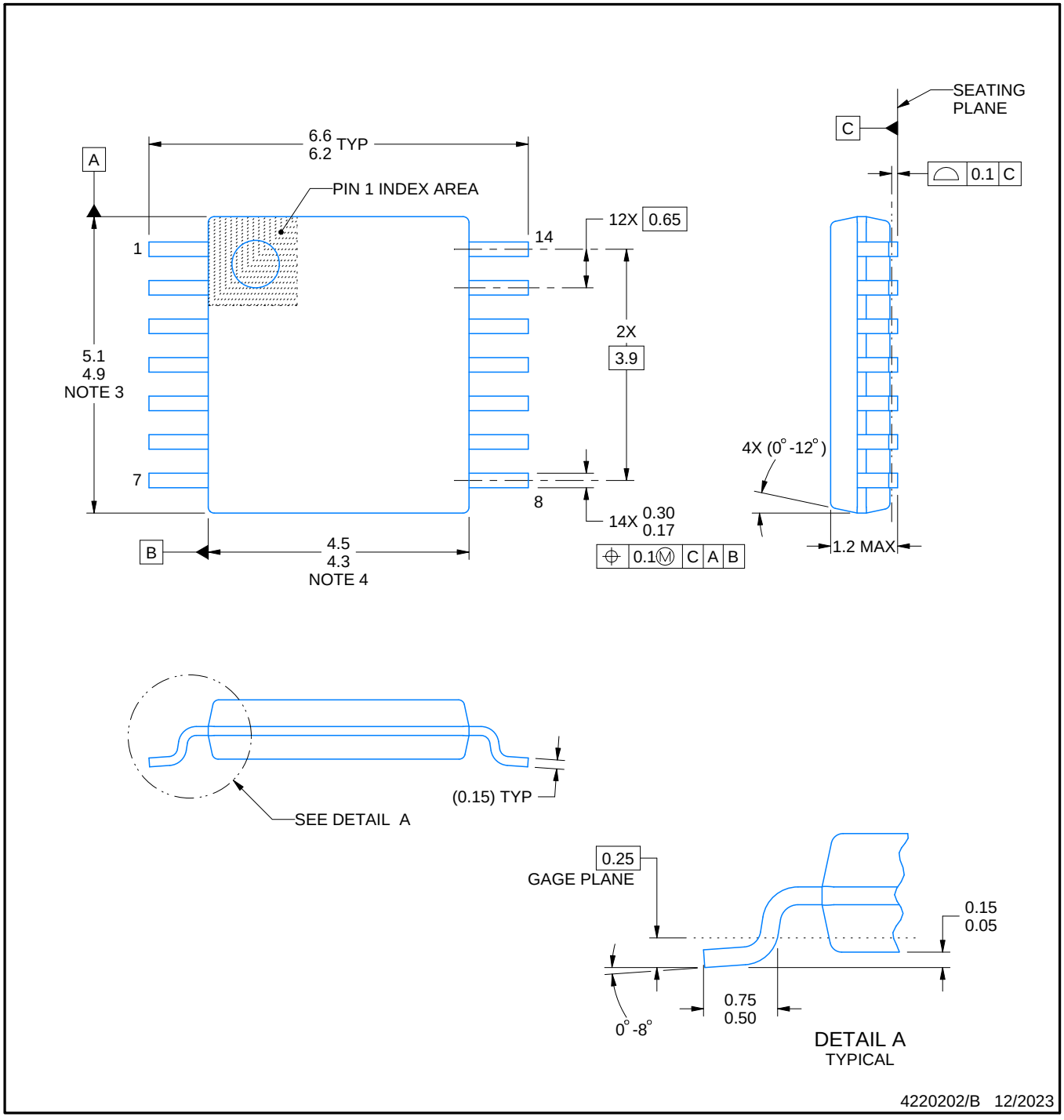
- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE OUTLINE

PW0014A

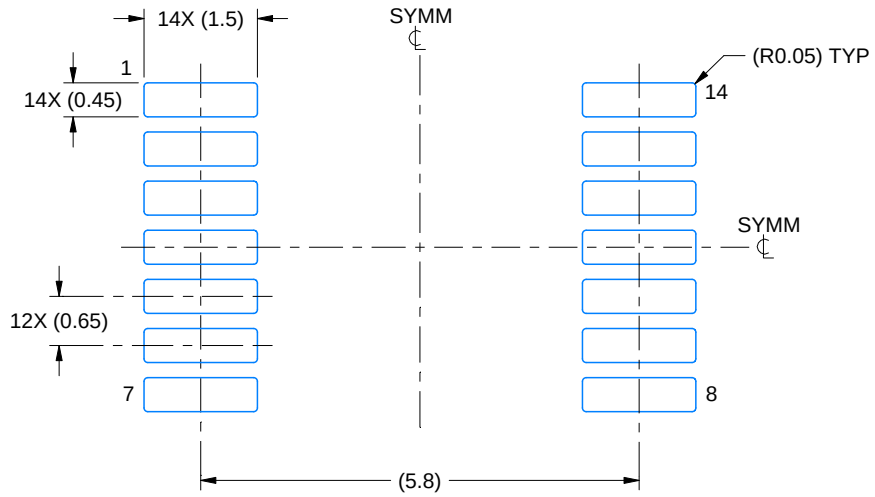
TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

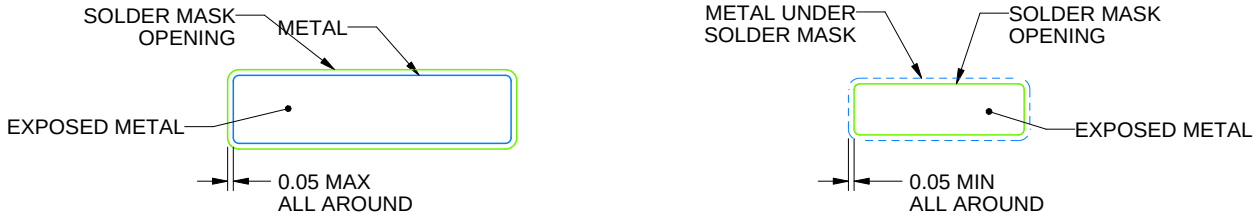


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

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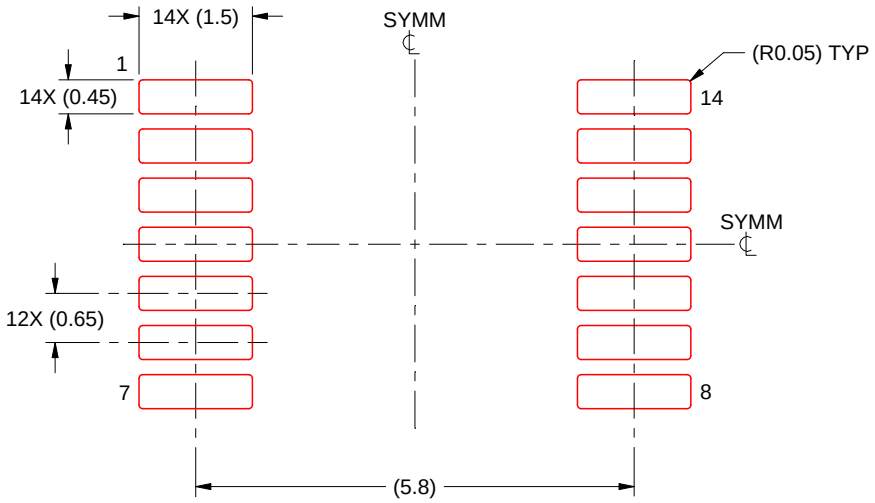
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

重要通知和免责声明

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